

N-Channel 20-V (D-S) MOSFET

Key Features:

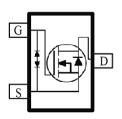
- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

- Power Routing
- Li Ion Battery Packs
- Level Shifting and Driver Circuits

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
20	13 @ V _{GS} = 4.5V	8.2	
	17 @ V _{GS} = 2.5V	7.2	









ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)					
Parameter			Limit	Units	
Drain-Source Voltage			20	V	
Gate-Source Voltage			±12		
O-retirence Dunin Comment 8	T _A =25°C		8.2		
Continuous Drain Current ^a	T _A =70°C	- I _D	6.5	Α	
Pulsed Drain Current ^b	•	I _{DM}	40		
Continuous Source Current (Diode Conduction) ^a		Is	2.1	Α	
Device Dissipation a	T _A =25°C	P _D	1.3	W	
Power Dissipation ^a	T _A =70°C	l P	0.8	"	
Operating Junction and Storage Temperature Range	•	T _J , T _{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	100	°C/W	
IMAXIIIIUIII JUIICUOII-to-Alfibierit	Steady State	I V OJA	166	C/VV	

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

MI2316NE

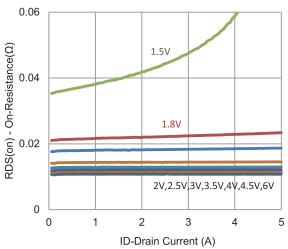
Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	0.4			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			±10	uA	
Zero Gate Voltage Drain Current		$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
	DSS	$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	12			Α	
Danier Course On Besistance 8	r	$V_{GS} = 4.5 \text{ V}, I_D = 2 \text{ A}$			13	mΩ	
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 1.6 \text{ A}$			17	11122	
Forward Transconductance ^a	g_{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 5 \text{ A}$		26		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 1.1 A, V _{GS} = 0 V		0.66		V	
Dynamic ^b							
Total Gate Charge	Q_g	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$		15		nC	
Gate-Source Charge	Q_{gs}	$I_{DS} = 10 \text{ V}, \text{ V}_{GS} = 4.3 \text{ V},$ $I_{D} = 2 \text{ A}$		2.0			
Gate-Drain Charge	Q_{gd}	ID - Z A		3.7			
Turn-On Delay Time	t _{d(on)}	$V_{DS} = 10 \text{ V}, R_{L} = 5 \Omega,$		177			
Rise Time	t _r	$V_{DS} = 10 \text{ V}, \text{ K}_{L} = 3 \Omega,$ $I_{D} = 2 \text{ A},$		330		ne	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 4.5 \text{ V}, R_{GEN} = 6 \Omega$		1929		ns	
Fall Time	t _f	V GEN - 4.5 V, T GEN - 0 12		897			
Input Capacitance	C _{iss}			1219			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ Mhz}$		149		рF	
Reverse Transfer Capacitance	C_{rss}]		122			

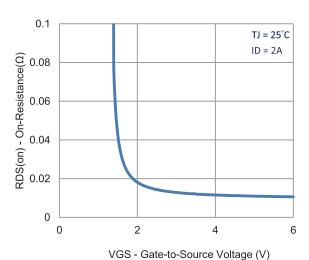
Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

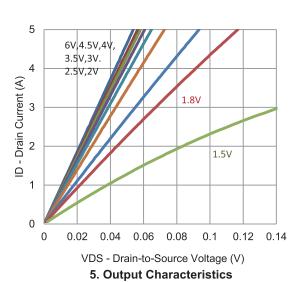
Typical Electrical Characteristics

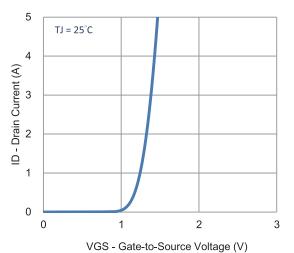


1. On-Resistance vs. Drain Current

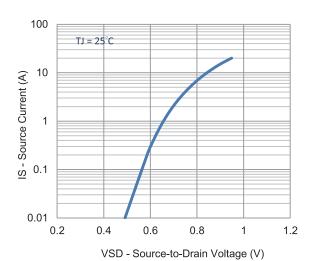


3. On-Resistance vs. Gate-to-Source Voltage

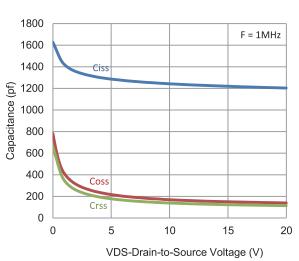




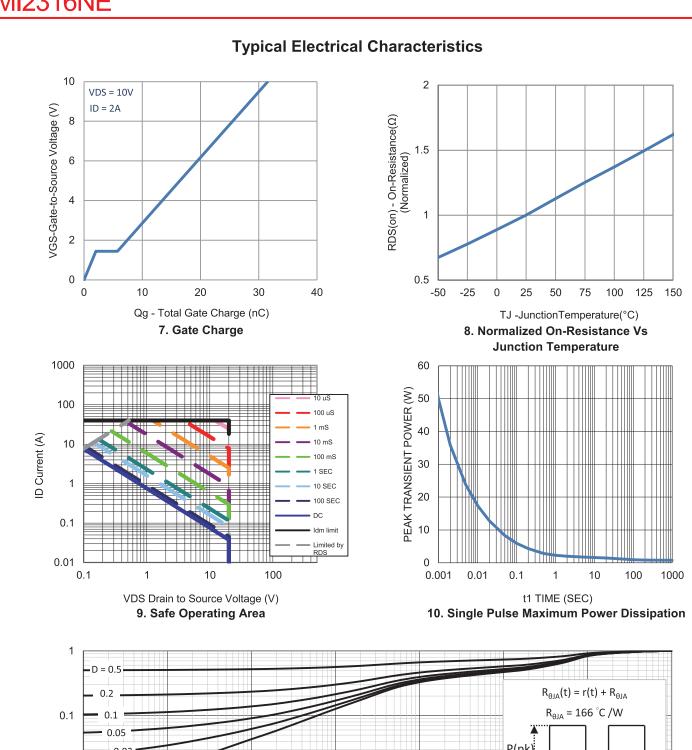
2. Transfer Characteristics

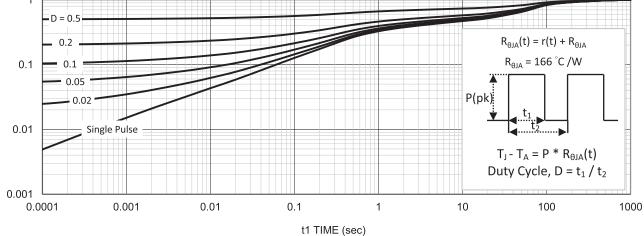


4. Drain-to-Source Forward Voltage



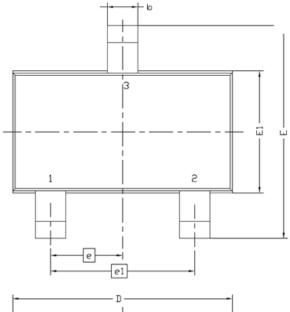
6. Capacitance



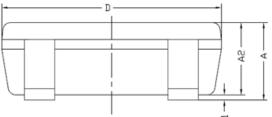


11. Normalized Thermal Transient Junction to Ambient

Package Information

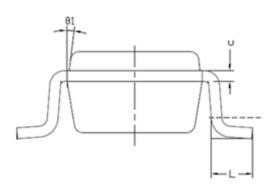


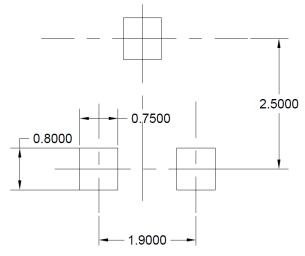
Symbol	MILLIMETERS		
Symbol	MIN	MAX	
Α	8.0	1.2	
A1	0	0.1	
A2	0.7	1.1	
b	0.3	0.5	
С	0.1	0.2	
D	2.7	3.1	
Е	2.6	3	
E1	1.4	1.8	
е	0.95 BSC		
e1	1.9 BSC		
L	0.3	0.6	
θ1	7° NOM		



Recommended Pad Layout

Note: Drain opening is recommended to be solder mask defined in a copper fill to provide improved thermal performance





Analog Power (APL) reserves the right to make changes without further notice to any products herein. APL makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does APL assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in APL data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. APL does not convey any license under its patent rights nor the rights of others. APL products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the APL product could create a situation where personal injury or death may occur. Should Buyer purchase or use APL products for any such unintended or unauthorized application, Buyer shall indemnify and hold APL and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that APL was negligent regarding the design or manufacture of the part. APL is an Equal Opportunity/Affirmative Action Employer.